

Switching Diode

BAS16P2T5G

The BAS16P2T5G Switching Diode is a spin-off of our popular SOT-23 three-leaded device. It is designed for switching applications and is housed in the SOD-923 surface mount package. This device is ideal for low-power surface mount applications, where board space is at a premium.

Features

- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Continuous Reverse Voltage	V_R	100	Vdc
Peak Forward Current	I_F	200	mAdc
Peak Forward Surge Current	$I_{FM(surge)}$	500	mAdc

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

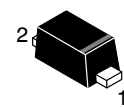
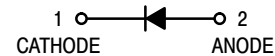
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient (Note 1) Total Power Dissipation @ $T_A = 25^\circ\text{C}$	$R_{\theta JA}$	520	$^\circ\text{C/W}$
	P_D	240	mW
Thermal Resistance, Junction-to-Ambient (Note 2) Total Power Dissipation @ $T_A = 25^\circ\text{C}$	$R_{\theta JA}$	175	$^\circ\text{C/W}$
	P_D	710	mW
Junction and Storage Temperature Range	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

1. Mounted onto a 4 in square FR-4 board 10 mm sq. 1 oz. Cu 0.06" thick single sided. Operating to steady state.
2. Mounted onto a 4 in square FR-4 board 1 in sq. 1 oz. Cu 0.06" thick single sided. Operating to steady state.



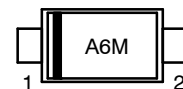
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SOD-923
CASE 514AB

MARKING DIAGRAM



A6 = Specific Device Code
M = Month Code

ORDERING INFORMATION

Device	Package	Shipping†
BAS16P2T5G	SOD-923 (Pb-Free)	8000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Reverse Voltage Leakage Current (V _R = 75 Vdc) (V _R = 100 Vdc) (V _R = 75 Vdc, T _J = 150°C) (V _R = 25 Vdc, T _J = 150°C)	I _R	–	1.0 100 50 30	μA _{dc}
Reverse Breakdown Voltage (I _{BR} = 100 μA _{dc})	V _(BR)	100	–	Vdc
Forward Voltage (I _F = 1.0 mA _{dc}) (I _F = 10 mA _{dc}) (I _F = 50 mA _{dc}) (I _F = 150 mA _{dc})	V _F	–	715 855 1000 1250	mV
Diode Capacitance (V _R = 0, f = 1.0 MHz)	C _D	–	2.0	pF
Forward Recovery Voltage (I _F = 10 mA _{dc} , t _r = 20 ns)	V _{FR}	–	1.75	Vdc
Reverse Recovery Time (I _F = I _R = 10 mA _{dc} , R _L = 50 Ω)	t _{rr}	–	6.0	ns
Stored Charge (I _F = 10 mA _{dc} to V _R = 5.0 Vdc, R _L = 500 Ω)	Q _S	–	45	pC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

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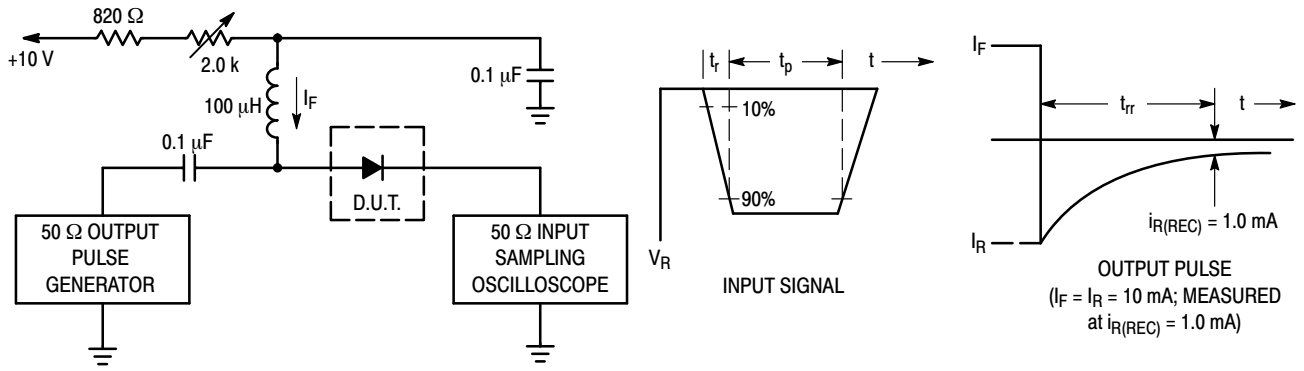


Figure 1. Recovery Time Equivalent Test Circuit

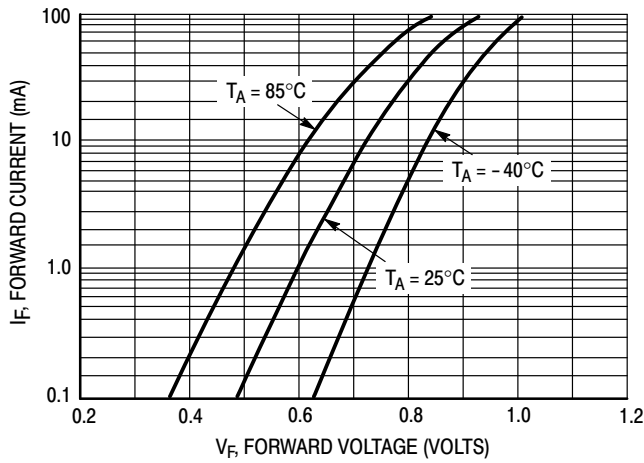


Figure 2. Forward Voltage

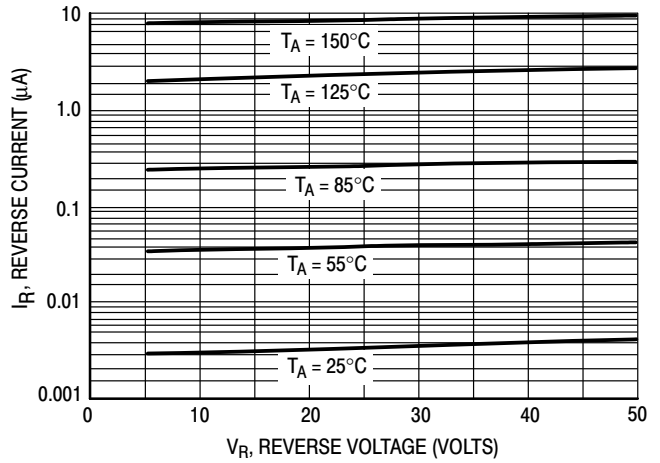


Figure 3. Leakage Current

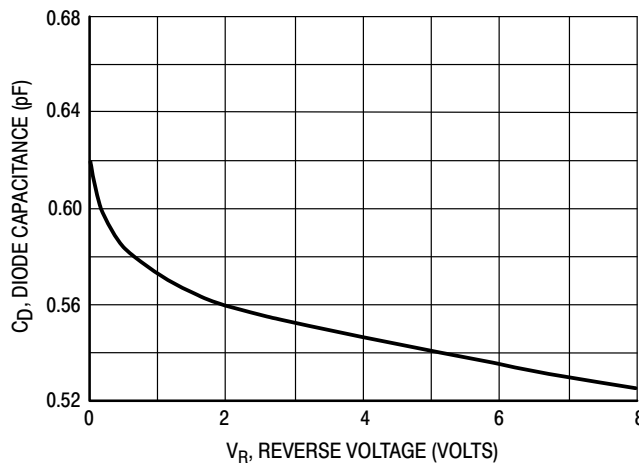


Figure 4. Capacitance

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